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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/842,694	04/27/2001	Isao Kobayashi	35.C13077 DI	9229
5514 7590 12/31/2003			EXAMINER	
FITZPATRICK CELLA HARPER & SCINTO 30 ROCKEFELLER PLAZA			MONDT, JOHANNES P	
NEW YORK, NY 10112			ART UNIT	PAPER NUMBER
			2826	
			DATE MAN ED 12/21/2002	

Please find below and/or attached an Office communication concerning this application or proceeding.

		16 /			
	Application No.	Applicant(s)			
	09/842,694	,			
Office Action Summary	09/842,094 Examiner	KOBAYASHI ET AL.			
,		Art Unit			
The MAILING DATE of this communication ap	Johannes P Mondt	2826			
Period for Reply	pour on the toron officer with the	orrespondence address	1		
A SHORTENED STATUTORY PERIOD FOR REPL THE MAILING DATE OF THIS COMMUNICATION. Extensions of time may be available under the provisions of 37 CFR 1. after SIX (6) MONTHS from the maling date of this communication. If the period for reply specified above is less than thirty (30) days, a reg. If NO period for reply is specified above, the maximum statutory period. Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailine aemed patent term adjustment. See 37 CFR 1.704(b). Status	136(a). In no event, however, may a reply be tir ply within the statutory minimum of thirty (30) day i will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. 10, 431 15, 6, 132).			
1) Responsive to communication(s) filed on 200	October 2003.				
2a) This action is FINAL . 2b) ⊠ This	action is non-final.				
Since this application is in condition for allowations closed in accordance with the practice under the	ance except for formal matters, pro Ex parte Quayle, 1935 C.D. 11, 45	osecution as to the merits is 53 O.G. 213.			
Disposition of Claims					
4) Claim(s) 1-3 and 7-11 is/are pending in the ap	oplication.				
4a) Of the above claim(s) is/are withdra	wn from consideration.		1		
5) Claim(s) is/are allowed.					
6)⊠ Claim(s) <u>1-3 and 7-11</u> is/are rejected.					
7) Claim(s) is/are objected to.					
8) Claim(s) are subject to restriction and/o	or election requirement.				
Application Papers					
9)⊠ The specification is objected to by the Examine					
10)☐ The drawing(s) filed on is/are: a)☐ acc					
Applicant may not request that any objection to the					
Replacement drawing sheet(s) including the correct					
11) The oath or declaration is objected to by the E	xaminer. Note the attached Office	Action or form PTO-152.			
Priority under 35 U.S.C. §§ 119 and 120					
12)⊠ Acknowledgment is made of a claim for foreigi a)□ All b)□ Some * c)⊠ None of:	n priority under 35 U.S.C. § 119(a))-(d) or (f).			
 Certified copies of the priority document 	s have been received.				
2. Certified copies of the priority document	s have been received in Application	on No			
 Copies of the certified copies of the prio application from the International Burea 	rity documents have been receive u (PCT Rule 17 2(a))	d in this National Stage			
* See the attached detailed Office action for a list	of the certified copies not received	d.			
13) Acknowledgment is made of a claim for domesting since a specific reference was included in the firm 37 CFR 1.78.	ic priority under 35 U.S.C. § 119(e st sentence of the specification or) (to a provisional application) in an Application Data Sheet.			
a) The translation of the foreign language pro	ovisional application has been rece	eived.			
14) Acknowledgment is made of a claim for domesti reference was included in the first sentence of the	c priority under 35 U.S.C. §§ 120 e specification or in an Application	and/or 121 since a specific n Data Sheet. 37 CFR 1.78.			
Attachment(s)					
1) Notice of References Cited (PTO-892)	4) 🔲 Interview Summary (PTO-413) Paper No(s).			
Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Informal Pa	stent Application (PTO-152)			

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DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 10/20/2003 has been entered.

Priority

2. It is noted that this application appears to claim subject matter disclosed in prior Application No. 09/185,717, filed 11/04/1998. A reference to the prior application must be inserted as the first sentence of the specification of this application or in an application data sheet (37 CFR 1.76), if applicant intends to rely on the filing date of the prior application under 35 U.S.C. 119(e) or 120. See 37 CFR 1.78(a). For benefit claims under 35 U.S.C. 120, the reference must include the relationship (i.e., continuation, divisional, or continuation-in-part) of all nonprovisional applications. Also, the current status of all nonprovisional parent applications referenced should be included.

If the application is a utility or plant application filed under 35 U.S.C. 111(a) on or after November 29, 2000, the specific reference to the prior application must be submitted during the pendency of the application and within the later of four months from the actual filing date of the application or sixteen months from the filing date of the

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prior application. If the application is a utility or plant application which entered the national stage from an international application filed on or after November 29, 2000. after compliance with 35 U.S.C. 371, the specific reference must be submitted during the pendency of the application and within the later of four months from the date on which the national stage commenced under 35 U.S.C. 371(b) or (f) or sixteen months from the filing date of the prior application. See 37 CFR 1.78(a)(2)(ii) and (a)(5)(ii). This time period is not extendable and a failure to submit the reference required by 35 U.S.C. 119(e) and/or 120, where applicable, within this time period is considered a waiver of any benefit of such prior application(s) under 35 U.S.C. 119(e), 120, 121 and 365(c). A priority claim filed after the required time period may be accepted if it is accompanied by a grantable petition to accept an unintentionally delayed claim for priority under 35 U.S.C. 119(e), 120, 121 and 365(c). The petition must be accompanied by (1) the reference required by 35 U.S.C. 120 or 119(e) and 37 CFR 1.78(a)(2) or (a)(5) to the prior application (unless previously submitted), (2) a surcharge under 37 CFR 1.17(t). and (3) a statement that the entire delay between the date the claim was due under 37 CFR 1.78(a)(2) or (a)(5) and the date the claim was filed was unintentional. The Director may require additional information where there is a question whether the delay was unintentional. The petition should be addressed to: Mail Stop Petition, Commissioner for Patents, P.O. Box 1450, Alexandria, Virginia 22313-1450.

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Specification

The Specification is objected to on the grounds explained above under "Priority".

Compliance with the requirements explained above under "Priority".

Response to Amendment

Amendment filed 10/20/2003 simultaneously with said Request for Continued Examination has been entered and forms the basis of this official action. Comments on Remarks in said Amendment are included below under "Response to Arguments".

Response to Arguments

3. In response to applicant's argument covering pages 7-10 in said Amendment under Remarks that the invention distinguishes over the prior art in at least two respects, i.e., ad a) on said photoelectric conversion mode in the newly added further limitation "for reading image information" and ad b) on said idling mode in the newly added further limitation "not for reading the image information", a recitation of the intended use of the claimed invention must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim. In a claim drawn to a process of making, the intended use must result in a manipulative difference as compared to the prior art. See *In re Casey*, 152 USPQ 235 (CCPA 1967) and *In re Otto*, 136 USPQ 458, 459 (CCPA 1963).

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4. Therefore, Applicant is urged to cast a distinction between the invention and the prior art in the form of a structural difference instead of through limitation of intended use.

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claim 1 is rejected under 35 U.S.C. 103(a) as being unpatentable over Endo et al (Doc. Id. No.: 09-098970; Japanese Patent No.: JP409098970A) in view of Umibe et al (Japanese Patent Application Number 06-313392; Application No.: 08-116044). Endo et al teach (cf. Drawing 6) a photoelectric converter (cf. title and abstract) of a laminated structure (laminated regions 602, 607, 604, 605 and 606 are laminated) comprising:

a first electrode layer 602 (G) (cf. section [0050], line 3);

an insulation layer 607 (cf. section [0053], lines 5-6) inherently blocking the passage of electrons and holes;

a photoelectric conversion semiconductor layer 604 (cf. section [0050], lines 5-9); an injection blocking layer 605 for blocking the injection of holes only (inherently so for this n-type semiconductor layer; cf. section [0050], lines 5-9) to the semiconductor photoelectric conversion layer at a time;

a second electrode layer 606 (D) (cf. section [0050], lines 5-9); and

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a switching means for operating the photoelectric converter by switching through operation modes including:

- (a) a photoelectric conversion mode (cf. Drawing 6(b)) for emitting electrons produced by the photon-induced electron-hole pair creation and thus accumulating holes in accordance with an amount of incident light (cf. section [0053], lines 1-17);
- (b) a refresh mode (cf. Drawing 6(a)) for emitting the other of the electrons or holes, namely the holes, from the photoelectric conversion element (cf. section [0052], lines 1-4).

Although Endo et al do not specifically teach to distinguish an idling mode for emitting electrons, hence the same of the electrons or holes as emitted by the photoelectric conversion mode, from the photoelectric conversion element, it would have been obvious to include said idling mode in view of Umibe et al, who teach the inclusion of an accumulation mode whereby the G electrode becomes open with regard to direct current, thus allowing any electrons created due to incidence of light to be accumulated as a charge on a capacitor (cf. Drawing 8 and section [0051].

Motivation, for including the teaching by Umibe et al in the invention by Endo et al, stems from the improved signal-to-noise (N/S) ratio (cf. section [0053]). Combination of said teaching with said invention is straightforward by including the open position for said G electrode. Success in the implementation of said combination can therefore be reasonably expected.

The further limitation that said photoelectric conversion mode emits one of the holes or the electrons, whichever one is emitted in the idling mode, generated in

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accordance with an amount of incident light <u>and for reading image information</u> is not necessarily taught by either references. *Neither is the similarly functional limitation* that said idling mode is <u>not for reading the image information</u>.

Both limitations only define intended use. However, a recitation of the intended use of the claimed invention must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim while in a claim drawn to a process of making, the intended use must result in a manipulative difference as compared to the prior art. See *In re Casey*, 152 USPQ 235 (CCPA 1967) and *In re Otto*, 136 USPQ 458, 459 (CCPA 1963).

1. Claims 2-3 and 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Endo et al and Umibe et al as applied to claim 1 above, and further in view of Takeda et al (5,591,963). As detailed above, claim 1 is unpatentable over Endo et al in view of Umibe et al. Neither Endo et al not Umibe et al necessarily teach the further limitation defined by claim 2. However, it would have been obvious to include said further limitation in view of Takeda et al, who teach that recombination as required for refresh mode is too rapid unless V_{UB} reaches a sufficiently large and positive value, upon which a photoelectric current can be detected, which is the essence of the photoelectric conversion mode (cf. column 10, lines 23-28).

It would have been obvious to include the teaching of Takeda et al because a minimum detection voltage is required for providing enough acceleration to the charge

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carriers created in the central intrinsic portion of the device. Combination, of the teaching by Takeda et al and the invention by Endo et al and Umibe et al, is straightforward by appropriate setting of the detection and idling voltage values.

With regard to claim 3: in the directions for operation as taught by Takeda et al operation with V_{UB} small but >0 (idling mode) is preceded in Takeda et al by operation with V_{UB}=0 (refresh mode) (cf. column 11, lines 60-65). Furthermore, irregardless of this teaching, it is generally understood by those of ordinary skills in the art that when common voltage regulators are used the transition from zero to a specific minimum positive voltage necessarily involves ramping up the voltage from zero to said minimum positive voltage, from which the further limitation as defined by claim 3 follows.

Therefore, claim 3 does not distinguish over the prior art.

With regard to claim 9: the potential V_{UB} in Takeda et al, which corresponds to the potential V_{dg} as defined by Applicant, can adopt zero, positive and negative values (cf. column 9, line 58 – column 10, line 2), which is understood by those of ordinary skills in the art to be a standard option in circuitry. Therefore, the further limitation as defined by claim 9 does not distinguish over the prior art.

3. Claim 7 is rejected under 35 U.S.C. 103(a) as being unpatentable over Endo et al in view of Umibe et al as applied to claim 1, and further in view of Furukawa et al (5,591,960) and Arita (4,740,710). As detailed above, claim 1 is unpatentable over Endo et al in view of Umibe et al.

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Endo et al nor Umibe et al do not specifically teach the application of the photoelectric converter such that a plurality of said photoelectric elements are arranged one-dimensionally or two-dimensionally with a switching element connected for each of the photoelectric conversion elements according to the further limitation of claim 7.

However, one- and two-dimensional arrays of photoelectric elements of this kind have long been known in the art of photoelectric converter systems, as witnessed by Furukawa et al, who teach a structure consisting of a combination of pluralities of photoelectric element array sections for the purpose of obtaining a high level signal with low noise (cf. column 4, lines 48-55) comprising a plurality of photoelectric conversion elements, arranged two-dimensionally (cf. column 6, lines 33-37) with a switching element connected for each of the photoelectric conversion elements (cf. column 6. lines 49-56) with all the photoelectric conversion elements being divided into a plurality of n blocs (n=3, the blocks being circuit sections 1002/1102, 2002/2102, and 4002/4102; cf. column 6, lines 49-59), a light signal of all the n x m photoelectric conversion elements (m being the number of photoelectric elements in each block; undefined in claim!) divided into n=3 blocks is output (inherent in any useful application of pluralities of photoelectric converters is their output) an intersection part of the matrix wiring, which when using the photoelectric converter essentially taught by Endo et al in view of Umibe et al comprises a laminated structure in which at least a first electrode layer, an insulating layer, a semiconductor layer and a second electrode layer are provided in this order. Furukawa et al do not necessarily teach that each layer of the laminated structure should be formed as prescribed by the further limitation of claim 7. However, from a cost

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production point of view it makes utter sense to form each said layer in this manner, because of ease of mass production; while Arita indeed teaches a photoelectric reading apparatus wherein a plurality of switches are each connected with one end of each of the photoelectric elements (diodes) (cf. column 7, lines 25-32 and Fig. 6). The teaching by Furukawa et al can be easily combined with the invention by Endo et al and Umibe et al, because creating arrays of photoelectric converters has long been considered standard in the art of photoelectric conversion apparatus, while *motivation* to include the teaching by Furukawa et al and Arita in the invention essentially taught by Endo et al and Umibe et al is prompted by the obvious advantage of high S/N ratio as obtained through including the teaching by Furukawa et al, and, furthermore, the obvious advantage of lower manufacturing cost as obtained through including the teaching by Arita.

It thus would have been obvious to one of ordinary skills in the art to modify the invention at the time it was made so as to include the further limitation of claim 7.

4. **Claim 8** is rejected under 35 U.S.C. 103(a) as being unpatentable over Endo et al (Doc. Identification No.: 09-098970) in view of Umibe et al (Japanese Patent Application No. 06-313392) and Perez-Mendez (5,596,198), or, in the alternative, in view of Umibe et al (loc. cit.) and Sashin (4,179,100). Endo et al teach (cf. Drawing 6) a photoelectric converter (cf. title and abstract) of a laminated structure (laminated regions 602, 607, 604, 605 and 606 are laminated) comprising:

a first electrode layer 602 (G) (cf. section [0050], line 3);

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an insulation layer 607 (cf. section [0053], lines 5-6) inherently blocking the passage of electrons and holes;

a photoelectric conversion semiconductor layer 604 (cf. section [0050], lines 5-9); an injection blocking layer 605 for blocking the injection of holes only (inherently so for this n-type semiconductor layer; cf. section [0050], lines 5-9) to the semiconductor photoelectric conversion layer at a time:

- a second electrode layer 606 (D) (cf. section [0050], lines 5-9); and
 a switching means for operating the photoelectric converter by switching through operation modes including:
- (a) a photoelectric conversion mode (cf. Drawing 6(b)) emitting electrons in accordance with an amount of incident light (cf. section [0053], lines 1-17);
- (b) a refresh mode (cf. Drawing 6(a)) for emitting holes, i.e., the other of the two types (electrons, holes) from the photoelectric conversion element (cf. section [0052], lines 1-4).

Endo et al do not specifically teach to include an idling mode for emitting electrons, i.e., the same charge carrier type as in the photoelectric conversion mode, from the photoelectric conversion element. However, it would have been obvious to include an idling mode in the invention by Endo et al in view of Umibe et al, who teach the inclusion of an accumulation mode whereby the G electrode becomes open with regard to direct current, thus allowing any electrons created due to incidence of light to be accumulated as a charge on a capacitor (cf. Drawing 8 and section [0051]).

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Motivation, for including the teaching by Umibe et al in the invention by Endo et al, stems from the improved signal-to-noise (N/S) ratio (cf. section [0053]). Combination of said teaching with said invention is straightforward by including the open position for said G electrode. Success in the implementation of said combination can therefore be reasonably expected.

Endo et al nor Umibe et al necessarily teach the photoelectric converter to comprise a signal processing means, display means, electric transmission means and radiation source as further defined by claim 8.

However, the use of signal processing for the purpose of generating corresponding image signals to various peripherals, signal recording for video/data recorder use, signal display for interactive video display are standard in the art of photoelectric imaging, as shown for instance by Perez-Mendez (cf. column 6, lines 28-36). Alternatively, the use of signal processing for the purpose of generating corresponding image signals to various peripherals, signal recording for video/data recorder use, signal display for interactive video display are standard in the art of photoelectric imaging, as shown by Sashin (4,179,100) (cf. Fig. 23 and column 15, line 64 – column 65, line 15). The examiner takes official notice that the use of electrical transmission for the transmission of data to other locations for remote processing or analysis is standard in the field. Finally, any photoelectric converter needs a radiation source for photon input, hence this aspect is inherent in a photoelectric converter system. Finally, any photoelectric converter resystem.

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The further limitation that said photoelectric conversion mode emits one of the holes or the electrons, whichever one is emitted in the idling mode, generated in accordance with an amount of incident light and for reading image information is not necessarily taught by either references. Neither is the similarly functional limitation that said idling mode is not for reading the image information.

Both limitations only define intended use. However, a recitation of the intended use of the claimed invention must result in a structural difference between the claimed invention and the prior art in order to patentably distinguish the claimed invention from the prior art. If the prior art structure is capable of performing the intended use, then it meets the claim while in a claim drawn to a process of making, the intended use must result in a manipulative difference as compared to the prior art. See *In re Casey*, 152 USPQ 235 (CCPA 1967) and *In re Otto*, 136 USPQ 458, 459 (CCPA 1963).

5. Claim 10 is rejected under 35 U.S.C. 103(a) as being unpatentable over Endo in view of Umibe et al and Perez-Mendez, or, in the alternative, in view of Umibe et al and Sashin et al as applied claim 8 above, and further in view of Takeuchi et al (JP363250634A; no images available on the PTO Data Base). As detailed above, claim 8 is unpatentable over Endo et al in view of Umibe et al and Perez-Mendez, or, in the alternative, over in view of Umibe et al and Sashin et al, none of whom, however, necessarily teach the use of phosphorus as a converter of wavelength of radiation as input into a photoelectric conversion element has long been known in the art as witnessed for instance by Japanese Patent to Takeuchi et al, who teach the conversion

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of X-rays to light in the visible range through the use of phosphorus prior to undergoing photoelectric conversion (cf. abstract and constitution), for the purpose of making it easier to read X-ray images through said conversion.

Motivation to include this teaching by Takeuchi et al is to reduce cost by making the system more easily operable (it is understood in the art that the radiation to be investigated for the case for which the invention by Takeuchi et al is intended, i.e., X-rays, is potentially a health risk). The teaching in this regard by Takeuchi et al can be easily combined with the invention of claim 8 through inclusion of a phosphorous or phosphorescent layer, which is standard in the light detection art. Success in combining the inventions can therefore be reasonably expected.

6. Claim 11 is rejected under 35 U.S.C. 103(a) as being unpatentable over Endo et al and Umibe et al as applied above to claim 1, and further in view of Hikiji et al (JP406029510A). As detailed above, claim 1 is unpatentable over Endo et al in view of Umibe et al.

Neither Endo et al nor Umibe et al necessarily teach the further limitation as defined by claim 11. However, TFT-driven photoelectric converters have long been known in the art of semiconductor image sensors, as witnessed for example by Hikiji et al, who teach the TFT-driven photoelectric converter (image sensor) to be made on the same substrate and with the same layer construction (cf. English Abstract, "Purpose", lines 1-4 and "Constitution", lines 1-7), thus increasing the compactness of the device. Motivation, to include the teaching by Hikiji et al, stems from the synergistic inclusion of

combination can therefore be reasonably expected.

the driver in the detector. Combinability is evident from the description of the formation of the TFT by Hikiji et al (see Abstract, "Constitution"). Success in implementing the

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Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Johannes P Mondt whose telephone number is: 703-306-0531 BEFORE February 4, 2004; and 571-272-1919 AFTER February 4, 2004. The examiner can normally be reached on 8:00 - 18:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan J Flynn can be reached on 703-308-6601 BEFORE February 4, 2004, and on 571-272-1915 AFTER February 4, 2004. The fax phone number for the organization where this application or proceeding is assigned is 703-308-5399.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-305-3900.

GUPERVISORY FOLENT EXAMINED TECHNOLOGY CENTER 2800

JPM December 26, 2003